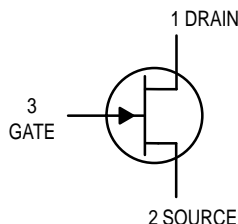
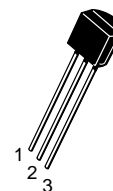


# JFET VHF Amplifier

## N-Channel — Depletion



**MPF102**



**CASE 29-04, STYLE 5**  
**TO-92 (TO-226AA)**

### MAXIMUM RATINGS

| Rating   | Symbol    | Value       | Unit                       |
|--|-----------|-------------|----------------------------|
| Drain-Source Voltage   | $V_{DS}$  | 25          | Vdc                        |
| Drain-Gate Voltage   | $V_{DG}$  | 25          | Vdc                        |
| Gate-Source Voltage  | $V_{GS}$  | -25         | Vdc                        |
| Gate Current   | $I_G$     | 10          | mAdc                       |
| Total Device Dissipation @ $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$     | 350<br>2.8  | mW<br>mW/ $^\circ\text{C}$ |
| Junction Temperature Range   | $T_J$     | 125         | $^\circ\text{C}$           |
| Storage Temperature Range  | $T_{stg}$ | -65 to +150 | $^\circ\text{C}$           |

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|----------------|--------|-----|-----|------|
|----------------|--------|-----|-----|------|

#### OFF CHARACTERISTICS

|  |               |        |              |                         |
|--|---------------|--------|--------------|-------------------------|
| Gate-Source Breakdown Voltage<br>( $I_G = -10\ \mu\text{Adc}$ , $V_{DS} = 0$ )   | $V_{(BR)GSS}$ | -25    | —            | Vdc                     |
| Gate Reverse Current<br>( $V_{GS} = -15\ \text{Vdc}$ , $V_{DS} = 0$ )<br>( $V_{GS} = -15\ \text{Vdc}$ , $V_{DS} = 0$ , $T_A = 100^\circ\text{C}$ ) | $I_{GSS}$     | —<br>— | -2.0<br>-2.0 | nAdc<br>$\mu\text{Adc}$ |
| Gate-Source Cutoff Voltage<br>( $V_{DS} = 15\ \text{Vdc}$ , $I_D = 2.0\ \text{nAdc}$ )   | $V_{GS(off)}$ | —      | -8.0         | Vdc                     |
| Gate-Source Voltage<br>( $V_{DS} = 15\ \text{Vdc}$ , $I_D = 0.2\ \text{mAdc}$ )  | $V_{GS}$      | -0.5   | -7.5         | Vdc                     |

#### ON CHARACTERISTICS

|  |           |     |    |      |
|--|-----------|-----|----|------|
| Zero-Gate-Voltage Drain Current <sup>(1)</sup><br>( $V_{DS} = 15\ \text{Vdc}$ , $V_{GS} = 0\ \text{Vdc}$ ) | $I_{DSS}$ | 2.0 | 20 | mAdc |
|--|-----------|-----|----|------|

#### SMALL-SIGNAL CHARACTERISTICS

|  |                     |              |           |                  |
|--|---------------------|--------------|-----------|------------------|
| Forward Transfer Admittance <sup>(1)</sup><br>( $V_{DS} = 15\ \text{Vdc}$ , $V_{GS} = 0$ , $f = 1.0\ \text{kHz}$ )<br>( $V_{DS} = 15\ \text{Vdc}$ , $V_{GS} = 0$ , $f = 100\ \text{MHz}$ ) | $ y_{fs} $          | 2000<br>1600 | 7500<br>— | $\mu\text{mhos}$ |
| Input Admittance<br>( $V_{DS} = 15\ \text{Vdc}$ , $V_{GS} = 0$ , $f = 100\ \text{MHz}$ )   | $\text{Re}(y_{is})$ | —            | 800       | $\mu\text{mhos}$ |
| Output Conductance<br>( $V_{DS} = 15\ \text{Vdc}$ , $V_{GS} = 0$ , $f = 100\ \text{MHz}$ )   | $\text{Re}(y_{os})$ | —            | 200       | $\mu\text{mhos}$ |
| Input Capacitance<br>( $V_{DS} = 15\ \text{Vdc}$ , $V_{GS} = 0$ , $f = 1.0\ \text{MHz}$ )  | $C_{iss}$           | —            | 7.0       | pF               |
| Reverse Transfer Capacitance<br>( $V_{DS} = 15\ \text{Vdc}$ , $V_{GS} = 0$ , $f = 1.0\ \text{MHz}$ )   | $C_{rss}$           | —            | 3.0       | pF               |

1. Pulse Test; Pulse Width  $\leq 630\ \text{ms}$ , Duty Cycle  $\leq 10\%$ .

POWER GAIN

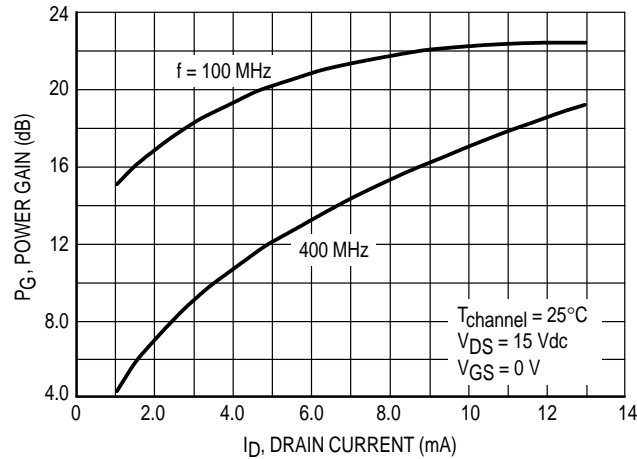
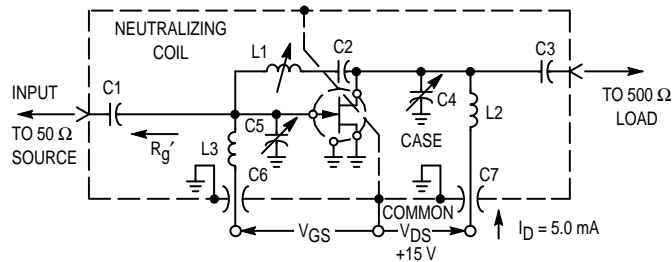


Figure 1. Effects of Drain Current



Adjust  $V_{GS}$  for  
 $I_D = 50 \text{ mA}$   
 $V_{GS} < 0 \text{ Volts}$

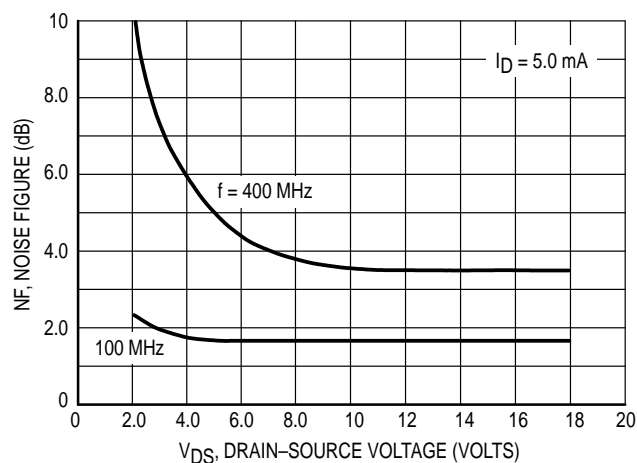
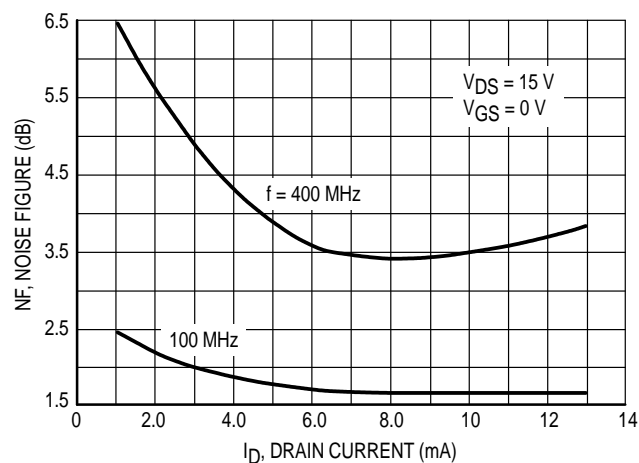
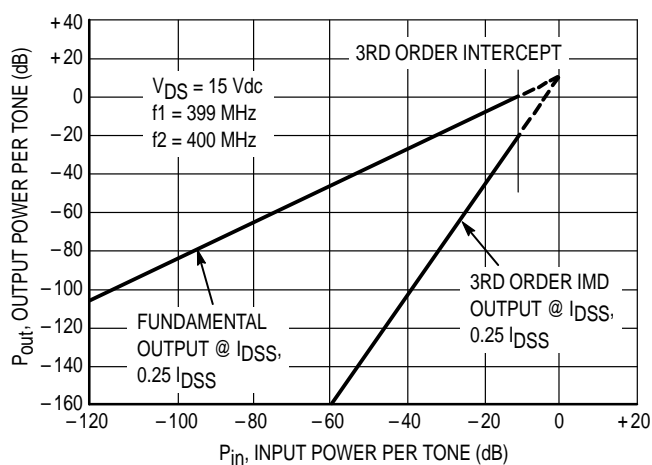
NOTE: The noise source is a hot-cold body  
(AIL type 70 or equivalent) with a  
test receiver (AIL type 136 or equivalent).

| Reference Designation | VALUE          |                    |
|-----------------------|----------------|--------------------|
|                       | 100 MHz        | 400 MHz            |
| C1                    | 7.0 pF         | 1.8 pF             |
| C2                    | 1000 pF        | 17 pF              |
| C3                    | 3.0 pF         | 1.0 pF             |
| C4                    | 1–12 pF        | 0.8–8.0 pF         |
| C5                    | 1–12 pF        | 0.8–8.0 pF         |
| C6                    | 0.0015 $\mu F$ | 0.001 $\mu F$      |
| C7                    | 0.0015 $\mu F$ | 0.001 $\mu F$      |
| L1                    | 3.0 $\mu H^*$  | 0.2 $\mu H^{**}$   |
| L2                    | 0.15 $\mu H^*$ | 0.03 $\mu H^{**}$  |
| L3                    | 0.14 $\mu H^*$ | 0.022 $\mu H^{**}$ |

- \*L1 17 turns, (approx. — depends upon circuit layout) AWG #28 enameled copper wire, close wound on 9/32" ceramic coil form. Tuning provided by a powdered iron slug.
- L2 4–1/2 turns, AWG #18 enameled copper wire, 5/16" long, 3/8" I.D. (AIR CORE).
- L3 3–1/2 turns, AWG #18 enameled copper wire, 1/4" long, 3/8" I.D. (AIR CORE).

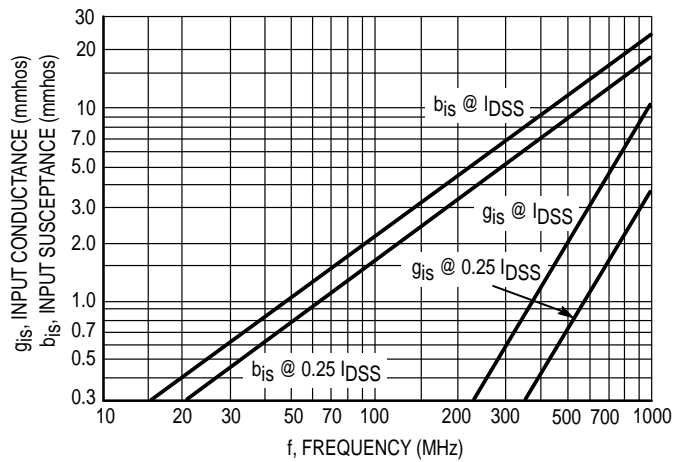
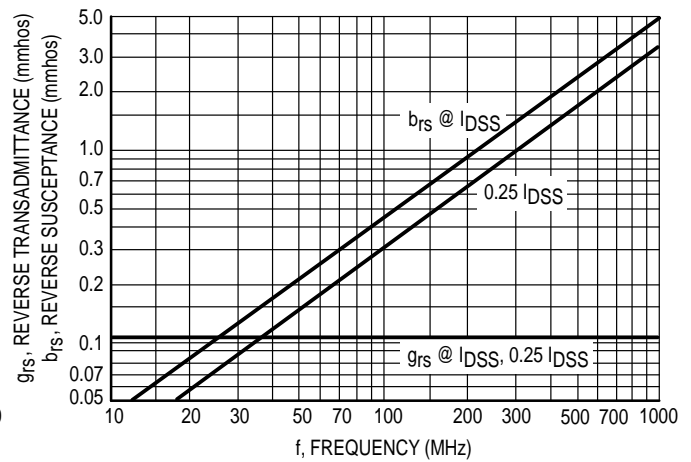
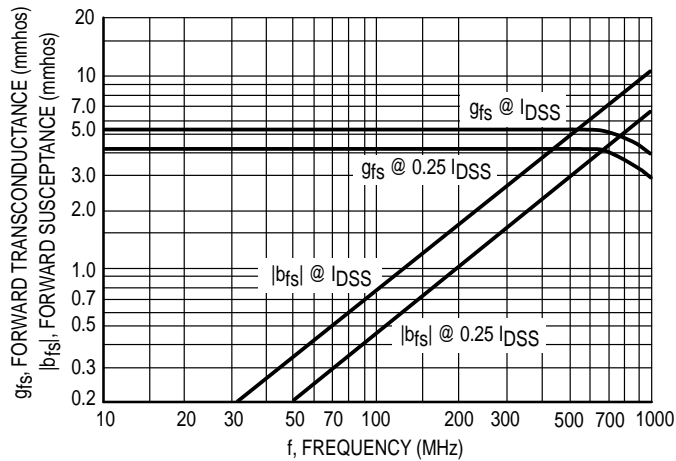
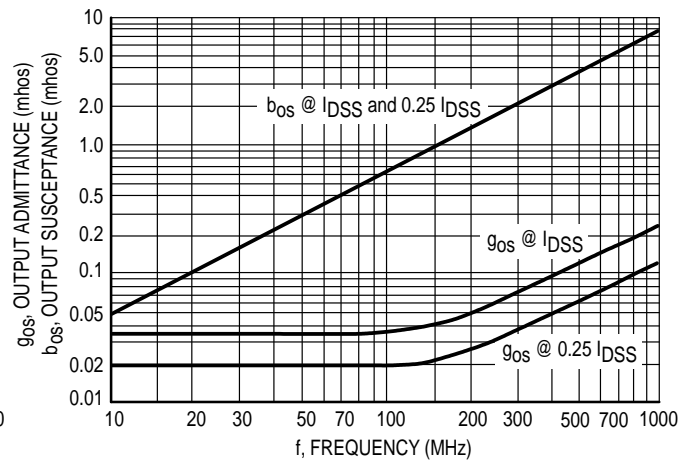
- \*\*L1 6 turns, (approx. — depends upon circuit layout) AWG #24 enameled copper wire, close wound on 7/32" ceramic coil form. Tuning provided by an aluminum slug.
- L2 1 turn, AWG #16 enameled copper wire, 3/8" I.D. (AIR CORE).
- L3 1/2 turn, AWG #16 enameled copper wire, 1/4" I.D. (AIR CORE).

Figure 2. 100 MHz and 400 MHz Neutralized Test Circuit

**NOISE FIGURE** $(T_{\text{channel}} = 25^{\circ}\text{C})$ **Figure 3. Effects of Drain-Source Voltage****Figure 4. Effects of Drain Current****INTERMODULATION CHARACTERISTICS****Figure 5. Third Order Intermodulation Distortion**

## COMMON SOURCE CHARACTERISTICS

## ADMITTANCE PARAMETERS

(V<sub>DS</sub> = 15 Vdc, T<sub>channel</sub> = 25°C)Figure 6. Input Admittance ( $y_{is}$ )Figure 7. Reverse Transfer Admittance ( $y_{rs}$ )Figure 8. Forward Transadmittance ( $y_{fs}$ )Figure 9. Output Admittance ( $y_{os}$ )

**COMMON SOURCE CHARACTERISTICS**  
**S-PARAMETERS**  
(V<sub>DS</sub> = 15 Vdc, T<sub>channel</sub> = 25°C, Data Points in MHz)

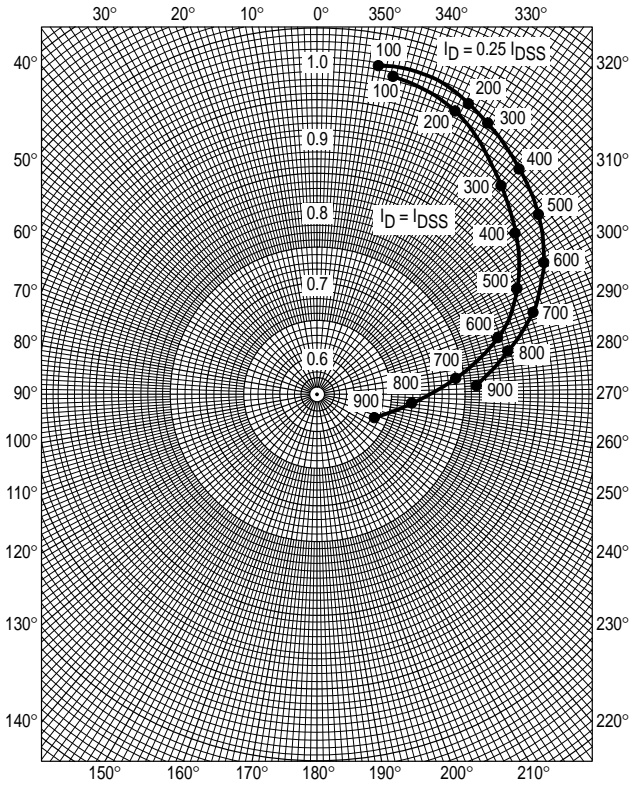


Figure 10. S<sub>11s</sub>

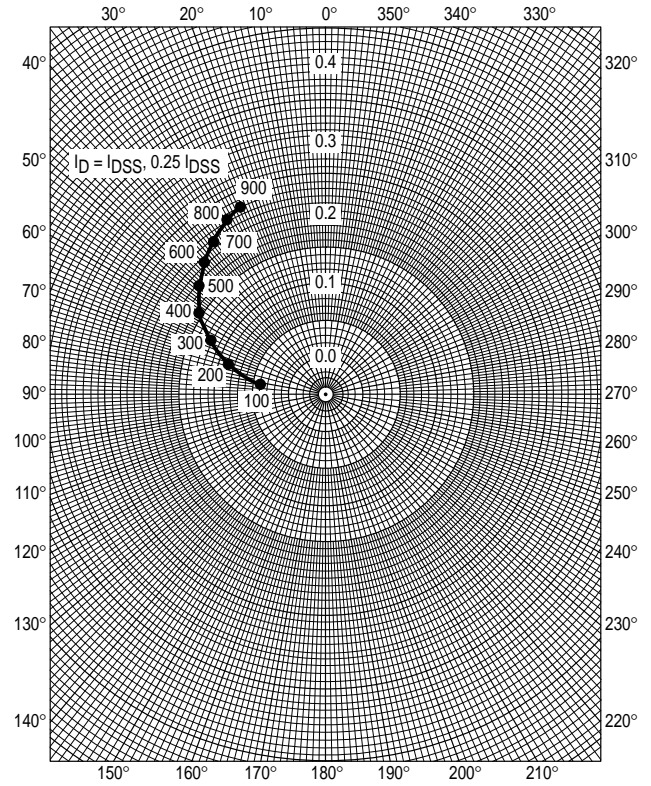


Figure 11. S<sub>12s</sub>

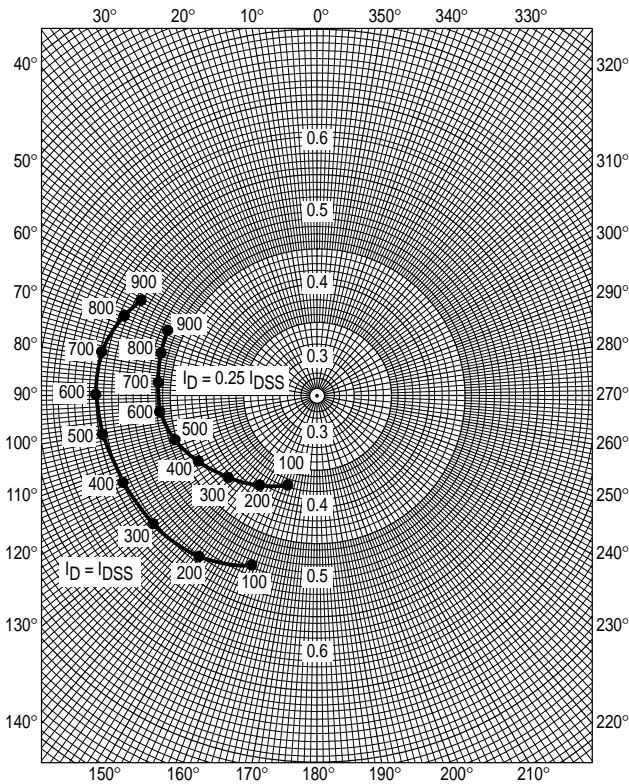


Figure 12. S<sub>21s</sub>

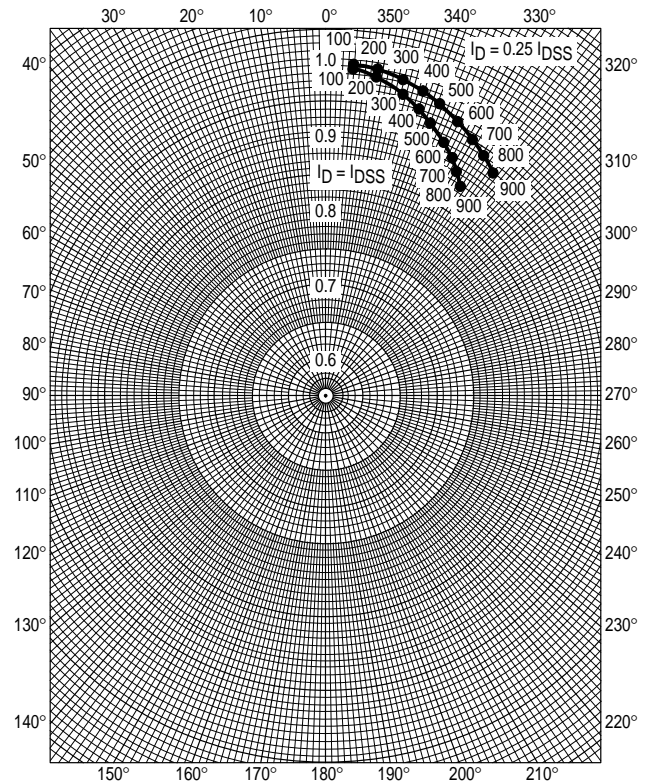
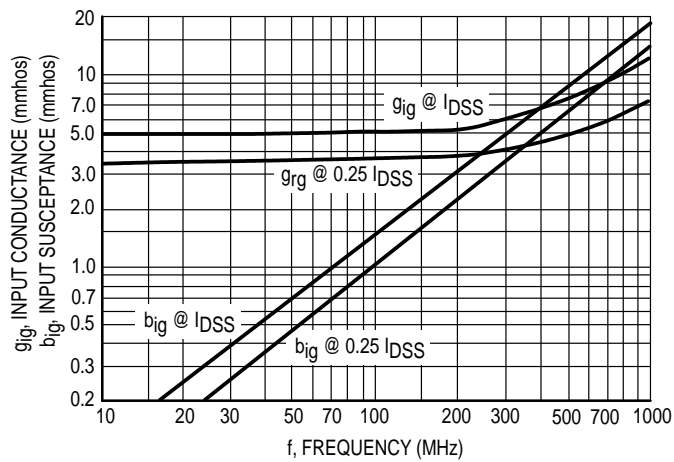
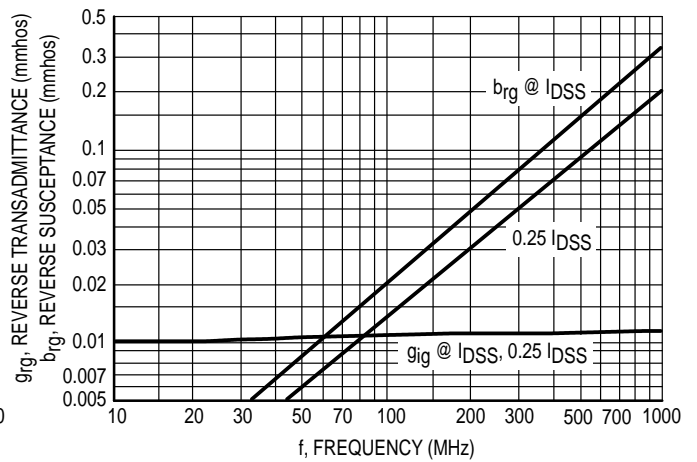
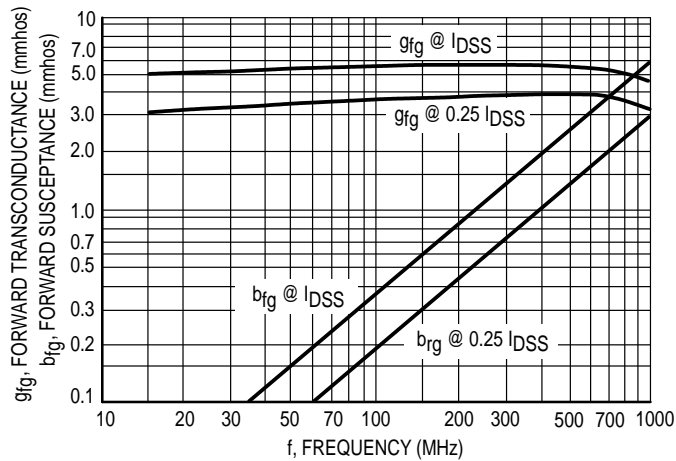
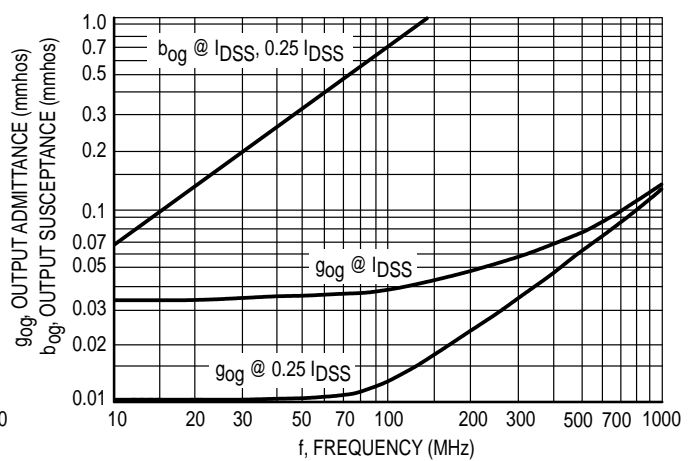


Figure 13. S<sub>22s</sub>

## COMMON GATE CHARACTERISTICS

## ADMITTANCE PARAMETERS

(V<sub>DG</sub> = 15 Vdc, T<sub>channel</sub> = 25°C)Figure 14. Input Admittance ( $y_{ig}$ )Figure 15. Reverse Transfer Admittance ( $y_{rg}$ )Figure 16. Forward Transfer Admittance ( $y_{fg}$ )Figure 17. Output Admittance ( $y_{og}$ )

# COMMON GATE CHARACTERISTICS

## S-PARAMETERS

( $V_{DS} = 15\text{ Vdc}$ ,  $T_{\text{channel}} = 25^\circ\text{C}$ , Data Points in MHz)

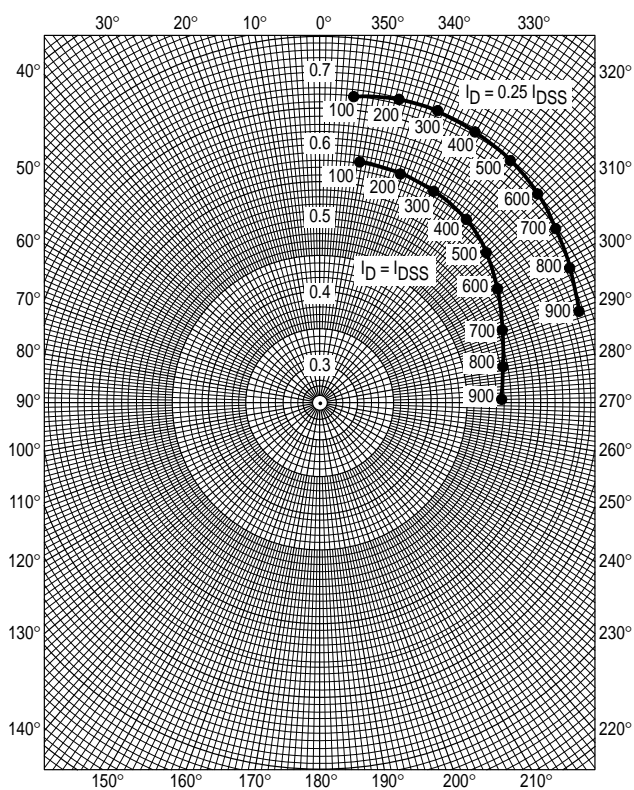


Figure 18.  $S_{11g}$

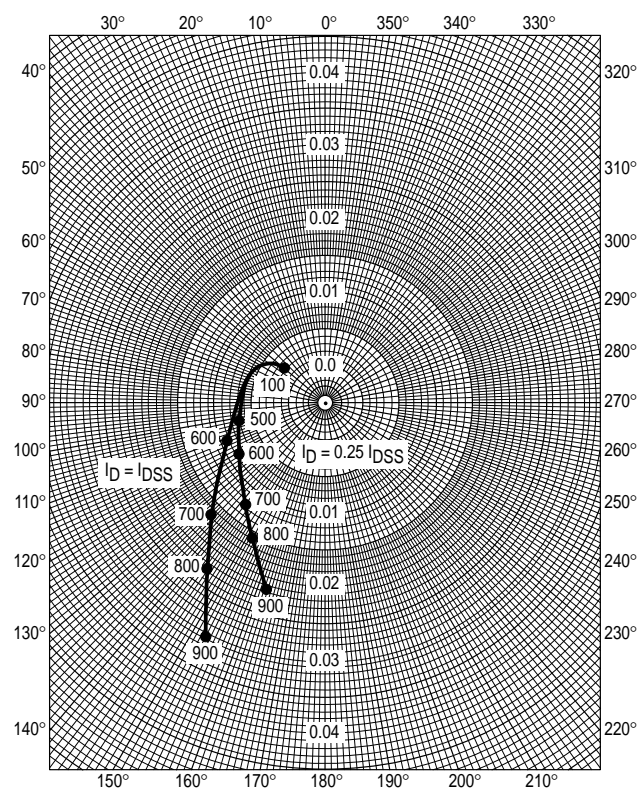


Figure 19.  $S_{12g}$

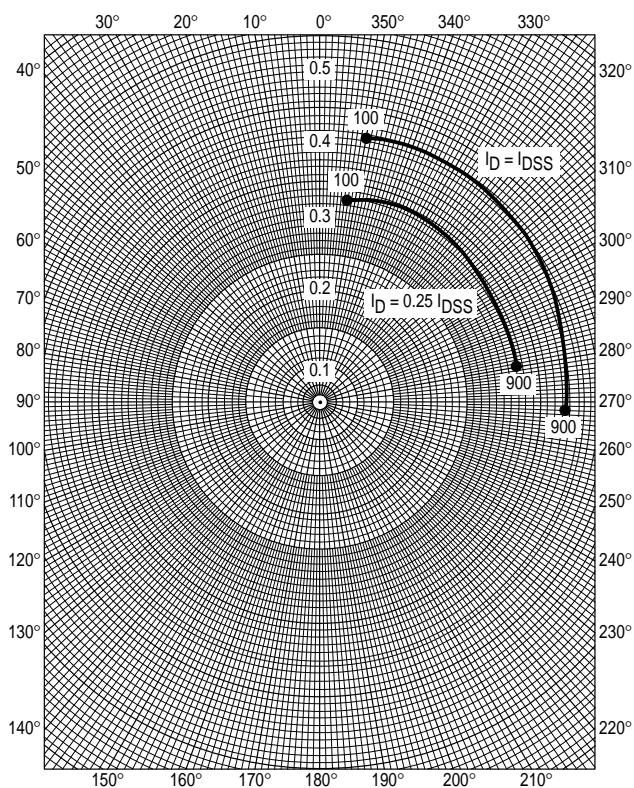


Figure 20.  $S_{21g}$

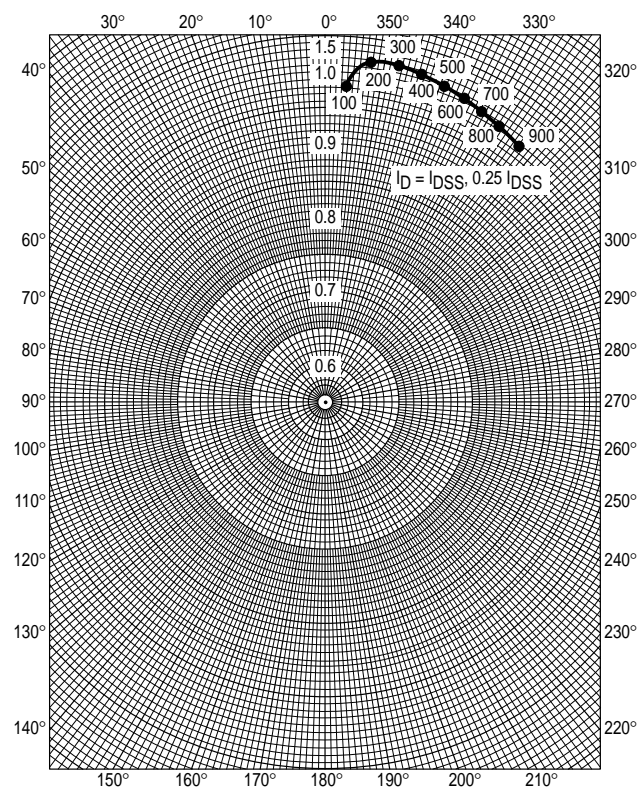
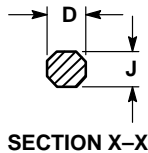
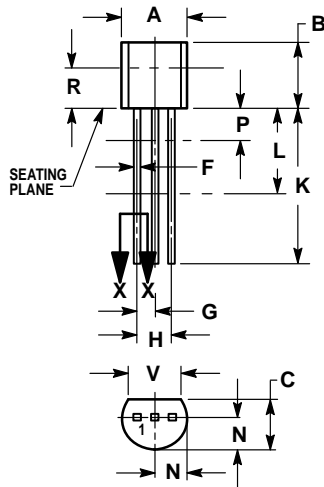


Figure 21.  $S_{22g}$

## PACKAGE DIMENSIONS



## NOTES:


1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K. MINIMUM LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

| DIM | INCHES |       | MILLIMETERS |      |
|-----|--------|-------|-------------|------|
|     | MIN    | MAX   | MIN         | MAX  |
| A   | 0.175  | 0.205 | 4.45        | 5.20 |
| B   | 0.170  | 0.210 | 4.32        | 5.33 |
| C   | 0.125  | 0.165 | 3.18        | 4.19 |
| D   | 0.016  | 0.022 | 0.41        | 0.55 |
| F   | 0.016  | 0.019 | 0.41        | 0.48 |
| G   | 0.045  | 0.055 | 1.15        | 1.39 |
| H   | 0.095  | 0.105 | 2.42        | 2.66 |
| J   | 0.015  | 0.020 | 0.39        | 0.50 |
| K   | 0.500  | —     | 12.70       | —    |
| L   | 0.250  | —     | 6.35        | —    |
| N   | 0.080  | 0.105 | 2.04        | 2.66 |
| P   | —      | 0.100 | —           | 2.54 |
| R   | 0.115  | —     | 2.93        | —    |
| V   | 0.135  | —     | 3.43        | —    |

**CASE 029-04  
(TO-226AA)  
ISSUE AD**

## STYLE 5:

- PIN 1. DRAIN
- SOURCE
- GATE

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